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# 74LVT16646 • 74LVTH16646 Low Voltage 16-Bit Transceiver/Register with 3-STATE Outputs

#### **General Description**

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The LVT16646 and LVTH16646 contains sixteen noninverting bidirectional registered bus transceivers providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Each byte has separate control inputs which can be shorted together for full

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Logic Diagrams

Symbol	Parameter	Value	Conditions	Units	
√ <sub>CC</sub>	Supply Voltage	-0.5 to +4.6		V	
VI	DC Input Voltage	-0.5 to +7.0		V	
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V	
		-0.5 to +7.0	Output in HIGH or LOW State (Note 3)	V	
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA	
l <sub>ок</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA	
l <sub>0</sub>	DC Output Current	64	V <sub>O</sub> > V <sub>CC</sub> Output at HIGH State		
		128	V <sub>O</sub> > V <sub>CC</sub> Output at LOW State	INA	
I <sub>CC</sub>	DC Supply Current per Supply Pin	±64		mA	
GND	DC Ground Current per Ground Pin	±128		mA	
Teto	Storage Temperature	-65 to +150		°C	

# **Recommended Operating Conditions**

Symbol	Parameter	Min	Max	Units	
V <sub>CC</sub>	Supply Voltage	2.7	3.6	V	
VI	Input Voltage	0	5.5	V	
I <sub>OH</sub>	HIGH-Level Output Current		-32	mΔ	
I <sub>OL</sub>	LOW-Level Output Current		64		
T <sub>A</sub>	Free-Air Operating Temperature	-40	85	°C	
$\Delta t/\Delta V$	Input Edge Rate, $V_{IN} = 0.8V-2.0V$ , $V_{CC} = 3.0V$	0	10	ns/V	

Note 2: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied. Note 3:  $\mathrm{I}_{\mathrm{O}}$  Absolute Maximum Rating must be observed.

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AC Electrical Characteristics						
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
Symbol	Parameter	$C_L = 50 \text{ pF}, \text{ R}_L =$	Units			
Note 10: Skew is defined specification applies to an	i as the absolute value of the difference between the ny outputs switching in the same direction, either HI	actual propagation delay for any two separate outputs of the same GH-to-LOW $(t_{\rm OSHL})$ or LOW-to-HIGH $(t_{\rm OSLH}).$	e device. The			
Capacitance	<b>e</b> (Note 11)					
Note 11: Capacitance is	measured at frequency f = 1 MHz, per MIL-STD-883	3, Method 3012.				



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